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09/896955

	Subclass	
	Class	
	ISSUE CLASSIFICATION	

PATENT NUMBER

U.S. UTILITY Patent Application

O.I.P.E. SCANNED	PATENT DATE <i>lsp TD3 G.A. Ed in ac 4 CP</i>
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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/896955	D	427	248.1	1762	<i>Meek</i>

APPLICANTS

Steven George
Jason Klaus

TITLE

Method for forming SiO₂ by chemical vapor deposition at room temperaturePTO-2040
12/99

ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)			
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)		
INTERNATIONAL CLASSIFICATION					
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TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent No. _____	(Primary Examiner) _____ (Date) _____			ISSUE FEE	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	(Legal Instruments Examiner) _____ (Date) _____			ISSUE BATCH NUMBER	

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